



MBR1035 THRU MBR10H100

10.0 AMPS. Schottky Barrier Rectifiers



Voltage Range
35 to 100 Volts
Current
10.0 Amperes

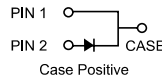
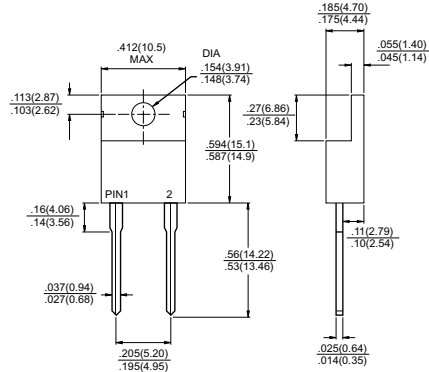
Features

- ✧ Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guardring for overvoltage protection
- ✧ High temperature soldering guaranteed:
250°C/10 seconds, 0.25" (6.35mm) from case

Mechanical Data

- ✧ Cases: JEDEC TO-220A molded plastic body
- ✧ Terminals: Lead solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs. max
- ✧ Weight: 0.08 ounce, 2.24 grams

TO-220A



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	MBR 1035	MBR 1045	MBR 1050	MBR 1060	MBR 10H90	MBR 10H100	Units
Maximum Recurrent Peak Reverse Voltage	35	45	50	60	90	100	V
Maximum RMS Voltage	24	31	35	42	63	70	V
Maximum DC Blocking Voltage	35	45	50	60	90	100	V
Maximum Average Forward Rectified Current See Fig. 1	10						A
Peak Repetitive Forward Current (Square Wave, 20KHz) at Tc=135°C	20.0						A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	150						A
Peak Repetitive Reverse Surge Current (Note 1)	1.0	0.5					A
Voltage Rate of Change (Rated V _R)	10,000						V/uS
Maximum Instantaneous Forward Voltage at (Note 2)							
I _F =10A, Tc=25°C	0.70	0.80		0.85			
I _F =10A, Tc=125°C	0.57	0.70		0.71		V	
I _F =20A, Tc=25°C	0.84	0.95		-			
I _F =20A, Tc=125°C	0.72	0.85		-			
Maximum Instantaneous Reverse Current @ Tc =25°C at Rated DC Blocking Voltage (Note 2) @Tc=125°C	0.1 15.0			0.0035 4.5			mA mA
Maximum Thermal Resistance, Junction to Case R _{θJC}	2.0						°C/W
Operating Junction Temperature Range T _J	-65 to +150						°C
Storage Temperature Range T _{STG}	-65 to +175						°C

Notes: 1. 2.0us Pulse Width, f=1.0 KHz

2. Pulse Test: 300us Pulse Width, 1% Duty Cycle

RATINGS AND CHARACTERISTIC CURVES (MBR1035 THRU MBR10H100)

FIG.1- FORWARD CURRENT DERATING CURVE

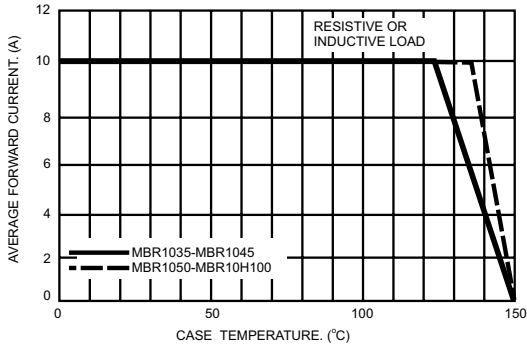


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

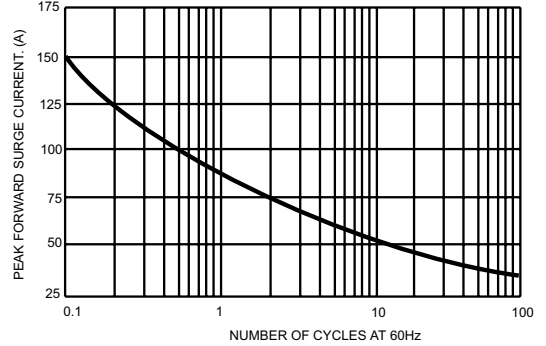


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

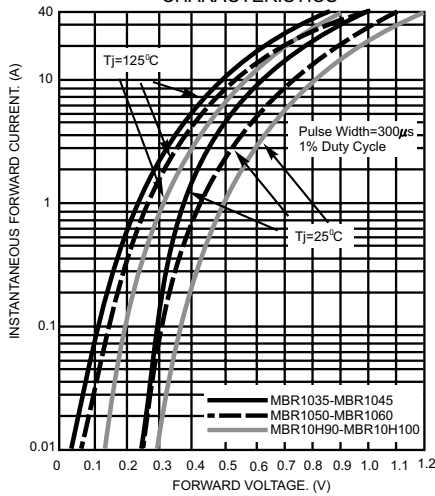


FIG.4- TYPICAL REVERSE CHARACTERISTICS

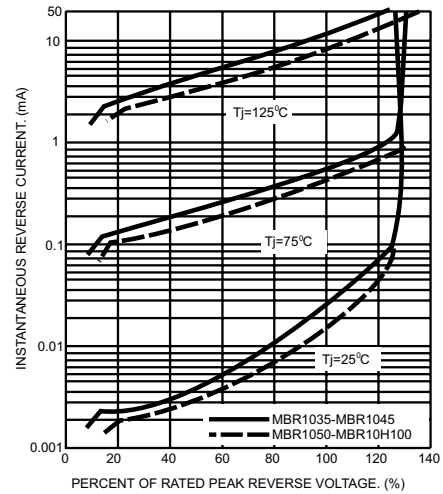


FIG.5- TYPICAL JUNCTION CAPACITANCE

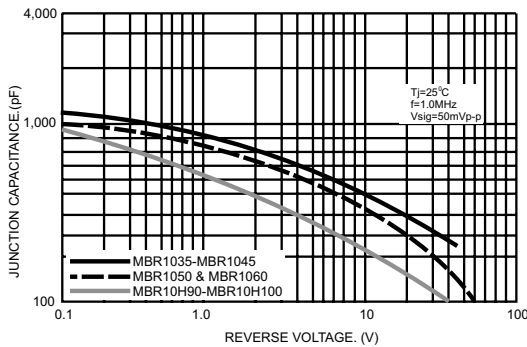


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTIC

